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## **BTA40**, **BTA41**, **BTB41**

#### 40 A standard TRIACs

#### **Features**

- High current TRIAC
- Low thermal resistance with clip bonding
- High commutation capability
- BTA series UL1557 certified (File ref: 81734)
- Packages are RoHS (2002/95/EC) compliant

#### **Applications**

- On/off function in static relays, heating regulation, induction motor starting circuits
- Phase control operations in light dimmers, motor speed controllers, and similar

#### **Description**

Available in high power packages, the BTA/BTB40-41 series is suitable for general purpose AC switching.

The BTA series provides an insulated tab (rated at 2500 V rms).

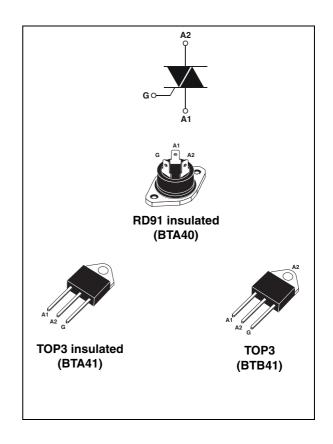


Table 1. Device summary

Symbol	Parameter	BTA40 <sup>(1)</sup>	BTA41 <sup>(1)</sup>	BTB41	Unit
I <sub>T(RMS)</sub>	On-state rms current	40	41	41	Α
V <sub>DRM</sub> /V <sub>RRM</sub>	Repetitive peak off-state voltage	600 and 800	600 and 800	600 and 800	V
I <sub>GT</sub>	Triggering gate current	50	50	50	mA

<sup>1.</sup> Insulated package

## 1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit	
1	On-state rms current	TOP3 $T_c = 95  ^{\circ}C$		40	Α	
I <sub>T</sub> (RMS)	(full sine wave)	RD91 / TOP ins.	T <sub>c</sub> = 80 °C	40		
_	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	400	А	
I <sub>TSM</sub>	current (full cycle, T <sub>j</sub> initial = 25 °C)	F = 60 Hz	t = 16.7 ms	420		
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		1000	A <sup>2</sup> s	
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz		50	A/μs	
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	$t_p = 10 \text{ ms}$ $T_j = 25 \text{ °C}$		V <sub>DSM</sub> /V <sub>RSM</sub> + 100	V	
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$ $T_j = 125  ^{\circ}C$		8	Α		
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 125$ °C		1	W		
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C	

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$	I - II - III IV	MAX.	50 100	mA
$V_{GT}$		ALL	MAX.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125 ^{\circ}\text{C}$ ALL		MIN.	0.2	V
I <sub>H</sub> (2)	I <sub>T</sub> = 500 mA		MAX.	80	mA
	l <sub>G</sub> = 1.2 l <sub>GT</sub>	I - III - IV	MAX.	70	- mA
I <sub>L</sub>	IG = 1.2 IGT	II	IVIAA.	160	IIIA
dV/dt <sup>(2)</sup>	V <sub>D</sub> = 67% V <sub>DRM</sub> gate open	T <sub>j</sub> = 125 °C	MIN.	500	V/µs
(dV/dt)c <sup>(2)</sup>	(dl/dt)c = 20 A/ms	T <sub>j</sub> = 125 °C	MIN.	10	V/µs

<sup>1.</sup> Minimum  $I_{\mbox{\scriptsize GT}}$  is guaranted at 5% of  $I_{\mbox{\scriptsize GT}}$  max.

<sup>2.</sup> for both polarities of A2 referenced to A1

Table 4. Static characteristics

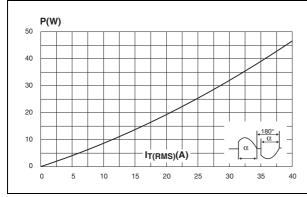
Symbol	Test conditions			Value	Unit
V <sub>T</sub> <sup>(1)</sup>	$I_{TM} = 60 \text{ A}$ $t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C	MAX.	1.55	V
V <sub>t0</sub> (2)	Threshold voltage	T <sub>j</sub> = 125 °C	MAX.	0.85	V
R <sub>d</sub> <sup>(2)</sup>	Dynamic resistance	T <sub>j</sub> = 125 °C	MAX.	10	mΩ
I <sub>DRM</sub>	V -V	T <sub>j</sub> = 25 °C	MAX.	5	μΑ
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 125 °C	IVIAA.	5	mA

- 1. Minimum  $I_{GT}$  is guaranted at 5% of  $I_{GT}$  max.
- 2. for both polarities of A2 referenced to A1

Table 5. Thermal resistance

Symbol	Test conditions		Value	Unit
D	RD91 (insulated) / TOP3 insulated		0.9	°C/W
R <sub>th(j-c)</sub>	Junction to case (AC)	TOP3	0.6	C/VV
R <sub>th(j-a)</sub>	Junction to ambient	Junction to ambient TOP3 / TOP3 insulated		°C/W

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)



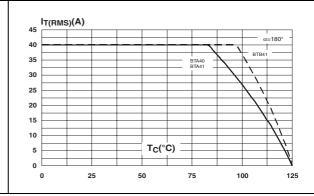


Figure 3. Relative variation of thermal impedance versus pulse duration

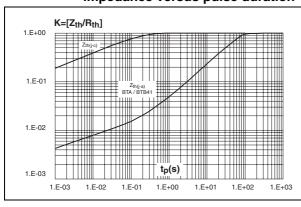


Figure 4. On-state characteristics (maximum values)

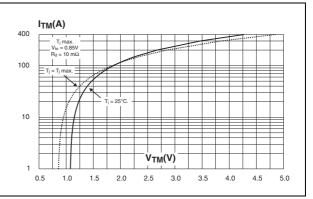


Figure 5. Surge peak on-state current versus Figure 6. number of cycles

Non-repetitive surge peak on-state current for a sinusoidal pulse and corresponding value of I<sup>2</sup>t

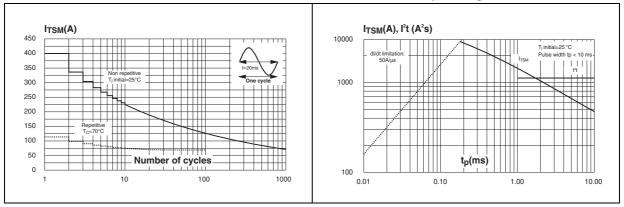


Figure 7. Relative variation of gate trigger, holding and latching current versus junction temperature

Figure 8. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)

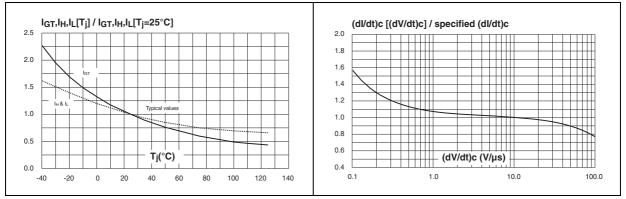
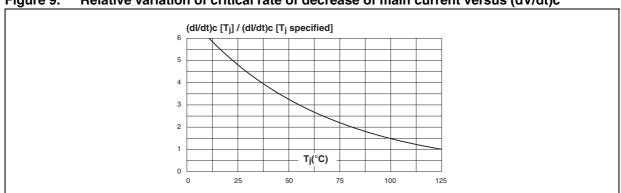
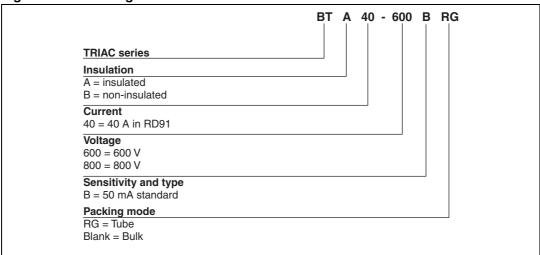


Figure 9. Relative variation of critical rate of decrease of main current versus (dV/dt)c



## 2 Ordering information scheme

Figure 10. Ordering information scheme



### 3 Package information

- Epoxy meets UL94, V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. TOP3 insulated and non-insulated dimensions

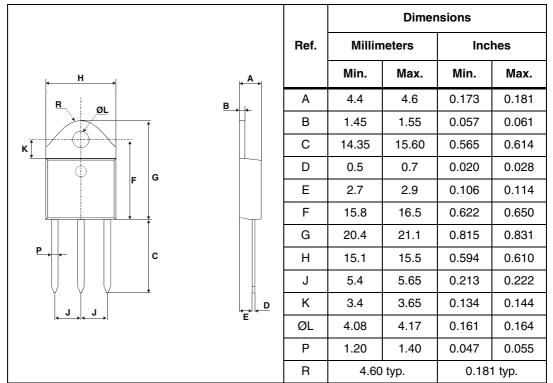
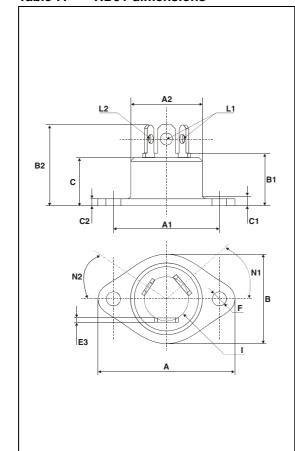


Table 7. RD91 dimensions



	Dimensions			
Ref.	Millin	Millimeters		hes
	Min.	Max.	Min.	Max.
Α	-	40.00	-	1.575
A1	29.90	30.30	1.177	1.193
A2	-	22.00	-	0.867
В	-	27.00	-	1.063
B1	13.50	16.50	0.531	0.650
B2	-	24.00	-	0.945
С	-	14.00	-	0.551
C1	-	3.50	-	0.138
C2	1.95	3.00	0.077	0.118
E3	0.70	0.90	0.027	0.035
F	4.00	4.50	0.157	0.177
I	11.20	13.60	0.441	0.535
L1	3.10	3.50	0.122	0.138
L2	1.70	1.90	0.067	0.075
N1	33°	43°	33°	43°
N2	28°	38°	28°	38°

# 4 Ordering information

Table 8. Ordering information

Order code <sup>(1)</sup>	Marking	Package	Weight	Base qty	Delivery mode
BTA40-xxxB	BTA40xxxB	RD91	20 g	25	Bulk
BTA41-xxxBRG	BTA41xxxB	TOP3 Ins.	4.5 g	30	Tube
BTB41-xxxBRG	BTB41xxxB	TOP3	4.5 g	30	Tube

<sup>1.</sup> xxx = voltage

# 5 Revision history

Table 9. Document revision history

Date	Revision	Changes
Sep-2003	5	Last update.
25-Mar-2005	6	TOP3 delivery mode changed from bulk to tube.
14-Oct-2005	7	${\rm T_{\rm C}}$ values for ${\rm I_{\rm T}}$ changed in Table 3. ECOPACK statement added.
10-Aug-2009	8	Updated <i>Table 2</i> to correctly place packages. Updated <i>Figure 2</i> . <i>Table 5</i> changed to correctly place TOP3. Updated ECOPACK statement.

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